

# GBU8005 THRU GBU810

## Glass Passivated Bridge Rectifiers

Reverse Voltage - 50 to 1000 Volts

Forward Current - 8.0 Amperes

### Features

- Glass passivated chip
- Low forward voltage drop
- Ideal for printed circuit board
- High surge current capability

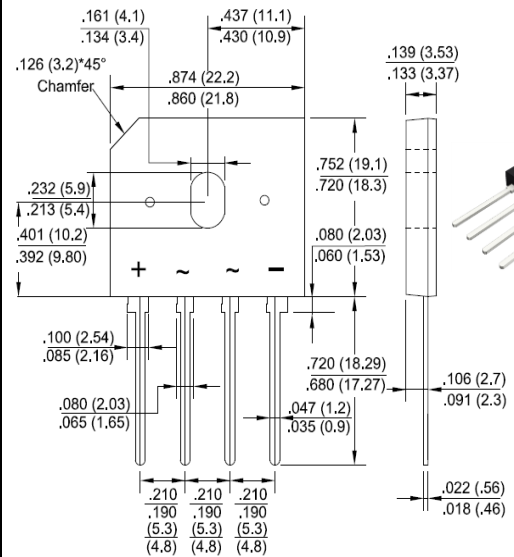
### Mechanical Data

- Polarity: Symbol marked on body
- Mounting position: Any
- AEC-Q101 qualified

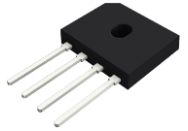
### Applications

- General purpose use in AC/DC bridge full wave rectification, for SMPS, lighting ballaster, adapter, etc.

### GBU



RoHS  
COMPLIANT



## Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristics	Symbol	GBU	GBU	GBU	GBU	GBU	GBU	GBU	Unit	
		8005	801	802	804	806	808	810		
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V	
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	v	
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	v	
Maximum Average Forward (with heatsink Note 2) Rectified Current @ T <sub>c</sub> =100°C (without heatsink)	I <sub>(AV)</sub>	8.0							2.9	A
Peak Forward Surge Current, 8.3mS Single Half Sine-Wave, Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	220								A
I <sup>2</sup> t Rating for Fusing (t<8.3mS)	I <sup>2</sup> t	200								A <sup>2</sup> s
Peak Forward Voltage per Diode at 4A DC	V <sub>F</sub>	1.0								V
Maximum DC Reverse Current at Rated @T <sub>J</sub> =25°C DC Blocking Voltage per Diode @T <sub>J</sub> =125°C	I <sub>R</sub>	5.0							500	μA
Typical Junction Capacitance per Diode (Note1)	C <sub>J</sub>	60								pF
Typical Thermal Resistance to Ambient (Note2)	R <sub>θJA</sub>	10								°C/W
Typical Thermal Resistance to case (Note2)	R <sub>θJC</sub>	2.2								
Typical Thermal Resistance to lead (Note2)	R <sub>θJL</sub>	3								
Operating Junction Temperature Range	T <sub>J</sub>	-55 to +150								°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150								°C

Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

2. Device mounted on 75mm\*75mm\*1.6mm Cu plate heatsink.

3. The typical data above is for reference only

GBU8\*-U-00-A001

Rev. 9, 22-Apr-2019

# Rating and Characteristic Curves

## GBU8005 THRU GBU810

Fig. 1 - Forward Current Derating Curve

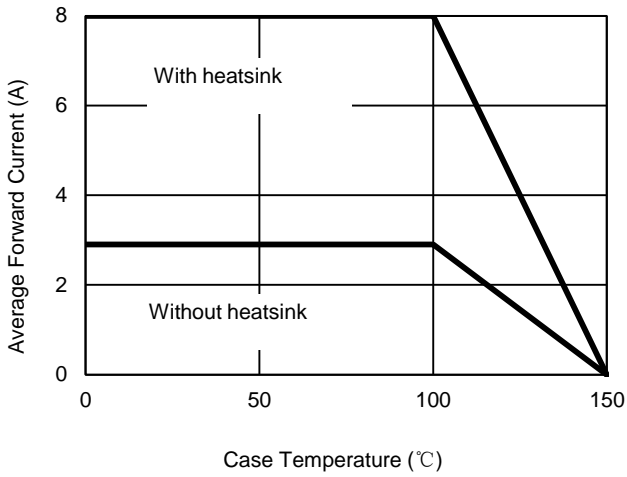


Fig. 2 - Maximum Non-Repetitive Surge Current

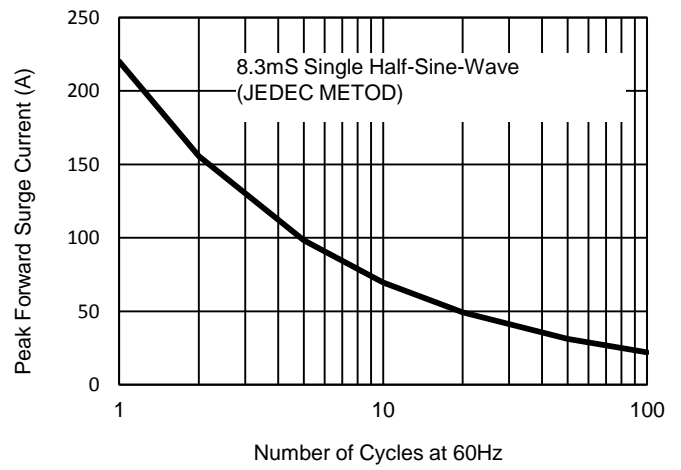


Fig. 3 - Typical Reverse Characteristics

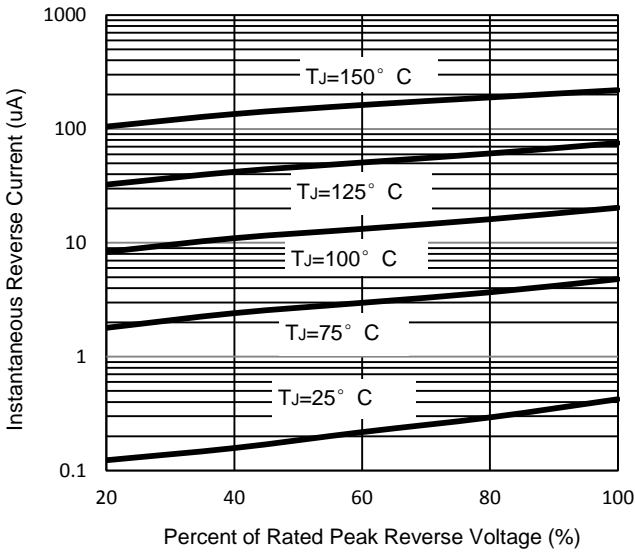


Fig. 4 - Typical Forward Characteristics

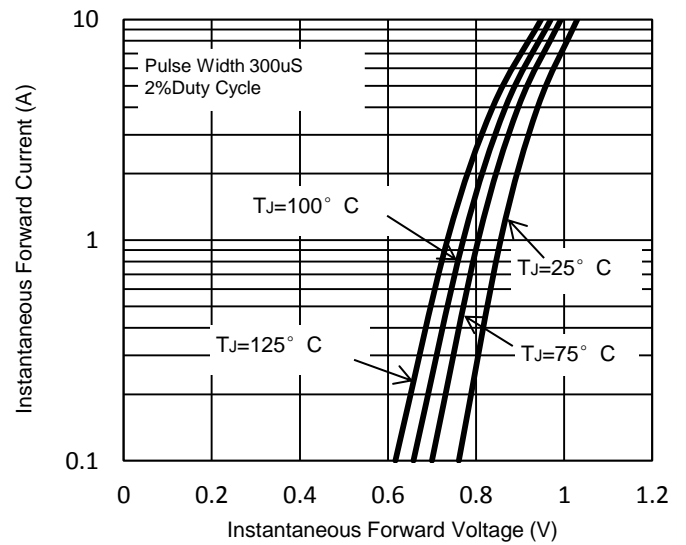
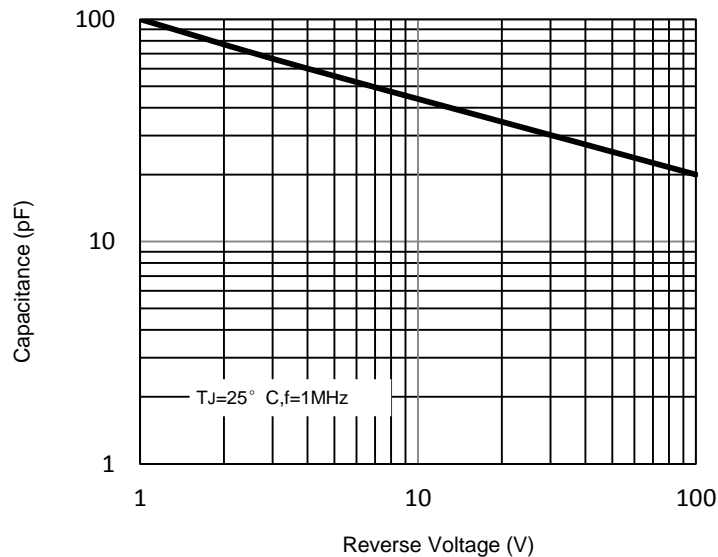


Fig. 5 - Typical Junction Capacitance



The curve above is for reference only.

